



#### 30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

60 A

#### **Features**

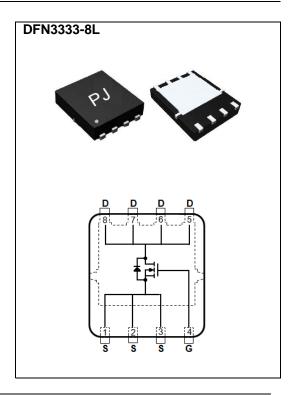
- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@10A<6m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_D@8A<9m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.001 ounces, 0.03 grams



# **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	30	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>C</sub> =25°C	l <sub>D</sub>	60	А	
	T <sub>C</sub> =100°C		38		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	240		
Power Dissipation	T <sub>C</sub> =25°C	Po	31	10/	
	T <sub>C</sub> =100°C		12.4	W	
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	15	Α	
	T <sub>A</sub> =70°C		12	Α	
Power Dissipation	T <sub>A</sub> =25°C	-	2.0	W	
Power Dissipation	T <sub>A</sub> =70°C	Pb	1.3		
Operating Junction and Storage	Temperature Range	$T_J, T_{STG}$	-55~150	°C	
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	$R_{ heta JC}$	4.0	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

Limited only By Maximum Junction Temperature





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS}=0V,I_{D}=250uA$	30	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	1.0	1.6	2.5	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =10A	-	5	6	mΩ	
		$V_{GS}$ =4.5 $V$ , $I_D$ =8 $A$	-	6.6	9		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =30V, $V_{GS}$ =0V	-	-	1.0	uA	
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 6)							
Total Gate Charge	$Q_g$	V <sub>DS</sub> =15V, I <sub>D</sub> =20A, V <sub>GS</sub> =4.5V (Note 1,2)	-	12	-	nC	
Gate-Source Charge	$Q_gs$		-	3.8	-		
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =4.3V	-	4.3	-		
Input Capacitance	Ciss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V,	-	1323	-	pF	
Output Capacitance	Coss		-	219	-		
Reverse Transfer Capacitance	Crss	I=1.0IVII IZ	-	136	-		
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DS}$ =15V,RL=1 $\Omega$ ,	-	5.0	-		
Turn-On Rise Time	t <sub>r</sub>	$V_{GS}$ =10V, $R_{G}$ =3.3 $\Omega$ (Note 2,3)	-	42	-	ns	
Turn-Off Delay Time	td <sub>(off)</sub>		-	36	-		
Turn-Off Fall Time	t <sub>f</sub>		-	5.5	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	ı		-	-	60	А	
Diode Forward Current	I <sub>S</sub>						
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A,V <sub>GS</sub> =0V	-	0.83	1	V	

#### NOTES:

- 1. Pulse width < 300us, Duty cycle < 2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial  $T_J$  =25°C.
- 4. The maximum current rating is package limited
- 5. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper
- 6. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

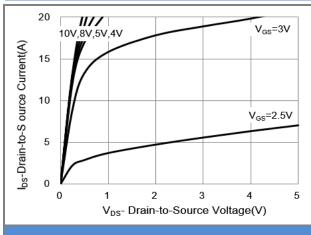
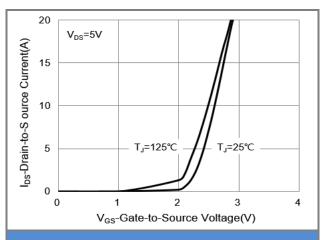


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

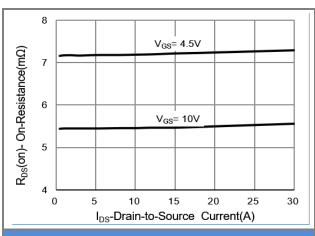


Fig.3 On-Resistance vs. Drain Current

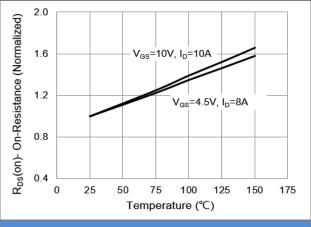


Fig.4 On-Resistance vs. Junction temperature

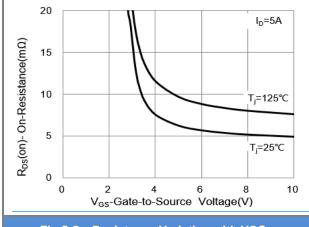


Fig.5 On-Resistance Variation with VGS.

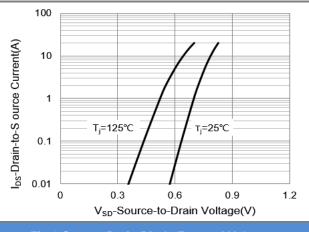


Fig.6 Source-Drain Diode Forward Voltage





#### TYPICAL CHARACTERISTIC CURVES

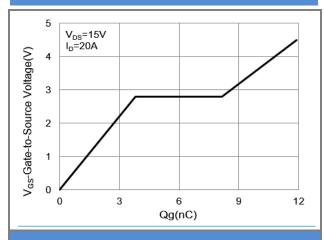


Fig.7 Gate-Charge Characteristics

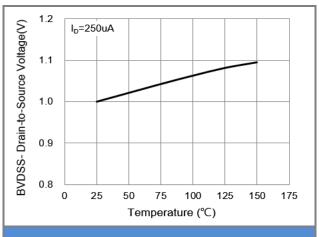


Fig.8 Breakdown Voltage Variation vs. Temperature.

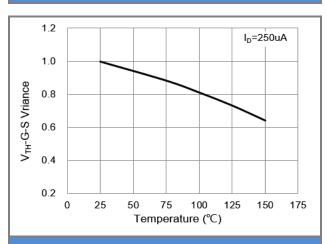


Fig.9 Threshold Voltage Variation with Temperature

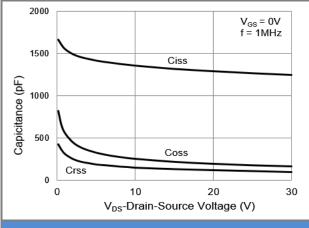
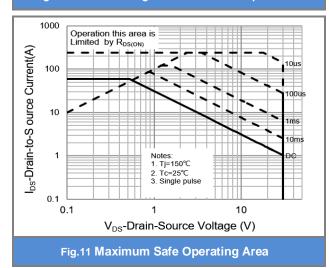


Fig.10 Capacitance vs. Drain-Source Voltage.







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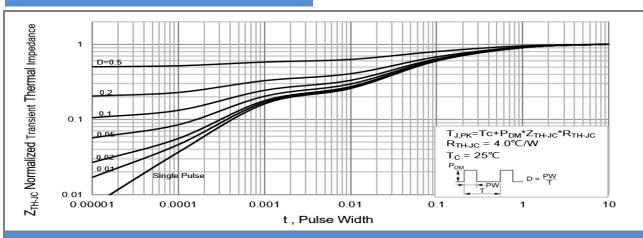


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

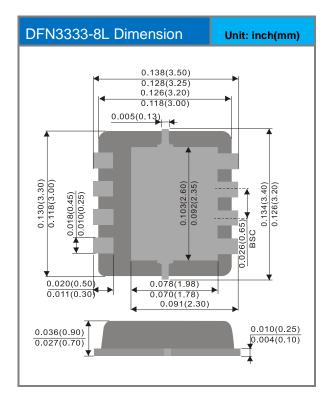


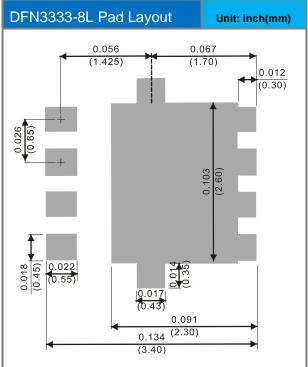


### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJQ4404P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4404	Halogen free	

### **Packaging Information & Mounting Pad Layout**









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